

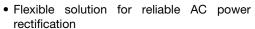
Thyristor High Voltage, Phase Control SCR, 30 A



PRIMARY CHARACTERISTICS					
I _{T(AV)}	20 A				
V_{DRM}/V_{RRM}	1200 V				
V_{TM}	1.3 V				
I _{GT}	45 mA				
T_J	-40 °C to 125 °C				
Package	TO-247AD 3L				
Circuit configuration	Single SCR				

FEATURES

- AEC-Q101 qualified
- Meets JESD 201 class 1A whisker test





- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- · On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

The VS-30TPS12LHM3 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications.

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	METER TEST CONDITIONS VALUES					
I _{T(AV)}	Sinusoidal waveform	usoidal waveform 20				
I _{RMS}		30	A			
V _{RRM} /V _{DRM}		1200	V			
I _{TSM}		300	A			
V _T	20 A, T _J = 25 °C	1.3	V			
dv/dt		500	V/µs			
di/dt		150	A/µs			
TJ		-40 to +125	°C			

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} / V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} / I _{DRM} AT 125 °C mA				
VS-30TPS12LHM3	1200	1300	10				



ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS		UNITS	
Maximum average on-state current	I _{T(AV)}	T _C = 95 °C, 180° conduction	half sine wave	20		
Maximum RMS on-state current	I _{RMS}			30	Α	
Maximum peak, one-cycle	,	10 ms sine pulse, rated V _{RRN}	₁ applied	250	A	
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage	reapplied	300		
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRN}	₁ applied	310	A ² s	
Maximum I-t for fusing	1-1	10 ms sine pulse, no voltage reapplied		442	A-8	
Maximum $I^2\sqrt{t}$ for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied		4420	A²√s	
Maximum on-state voltage drop	V_{TM}	20 A, T _J = 25 °C		1.3	V	
On-state slope resistance	r _t			12	mΩ	
Threshold voltage	V _{T(TO)}	T _J = 125 °C		1.0	V	
Maximum reverse and direct leakage	1 /1	T _J = 25 °C	\/ - rotod \/ / \/	0.5		
current	I _{RM} /I _{DM}	T _J = 125 °C	$V_R = \text{rated } V_{RRM} / V_{DRM}$	10	A	
Maximum holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C		150	mA	
Maximum latching current	IL	Anode supply = 6 V, resistive load, T _J = 25 °C		200		
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, linear to 80 % V_{DRM} , R_g -k = open		500	V/µs	
Maximum rate of rise of turned-on current	dl/dt		-		A/µs	

TRIGGERING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum peak gate power	P _{GM}		8.0	W		
Maximum average gate power	P _{G(AV)}		2.0	VV		
Maximum peak positive gate current	+I _{GM}		1.5	Α		
Maximum peak negative gate voltage	-V _{GM}		10	V		
	I _{GT}	Anode supply = 6 V, resistive load, $T_J = -10 ^{\circ}\text{C}$	60	mA		
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	45			
		Anode supply = 6 V, resistive load, T _J = 125 °C	20			
	V _{GT}	Anode supply = 6 V, resistive load, $T_J = -10 ^{\circ}\text{C}$	2.5			
Maximum required DC gate voltage to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C		V		
10 11990		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V		
Maximum DC gate voltage not to trigger V _G		T 405 00 V				
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = rated value		mA		

SWITCHING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9				
Typical reverse recovery time	t _{rr}	T _{.I} = 125 °C	4	μs			
Typical turn-off time	tq	1J = 125 C	110				



THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		METER SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to 125	°C	
Maximum thermal resistation to case	resistance, R _{thJC}		DC anavation	0.8		
Maximum thermal resistance, junction to ambient		R _{thJA} DC operation		40	°C/W	
Maximum thermal resistate case to heatsink	ximum thermal resistance, e to heatsink		Mounting surface, smooth and greased	0.2		
Approximate weight				6	g	
Approximate weight				0.21	OZ.	
Mounting torque	minimum			6 (5)	kgf · cm	
Mounting torque	maximum			12 (10)	(lbf · in)	
Marking device Case style TO-247AD 3L 30TPS		S12LH				

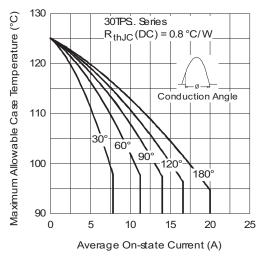


Fig. 1 - Current Rating Characteristics

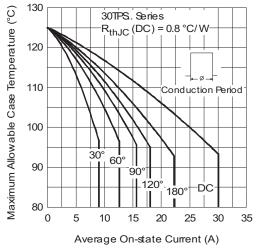


Fig. 2 - Current Rating Characteristics

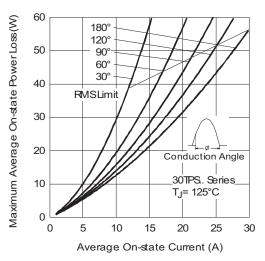


Fig. 3 - On-State Power Loss Characteristics

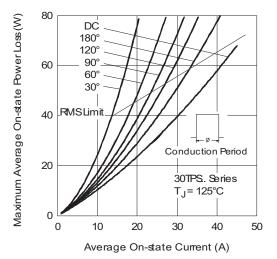


Fig. 4 - On-State Power Loss Characteristics

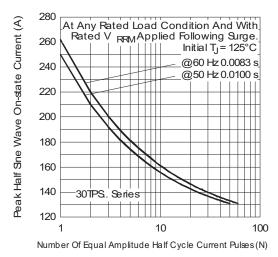


Fig. 5 - Maximum Non-Repetitive Surge Current

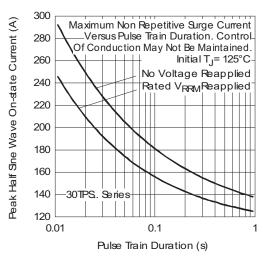


Fig. 6 - Maximum Non-Repetitive Surge Current

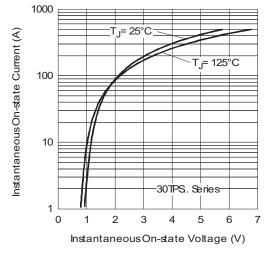


Fig. 7 - On-State Voltage Drop Characteristics

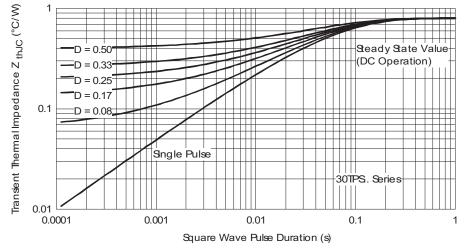


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

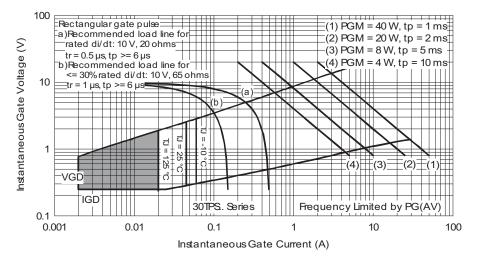
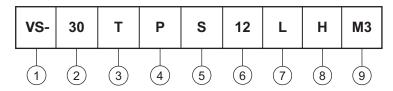


Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (30 = 30 A)
- 3 Circuit configuration:

T = Thyristor

- 4 P = TO-247 package
- 5 Type of silicon:

S = Standard recovery rectifier

- 6 Voltage code x 100 = V_{RRM} --------- 12 = 1200 V
- 7 Package L = long lead
- 8 H = AEC-Q101 qualified
- 9 Environmental digit:

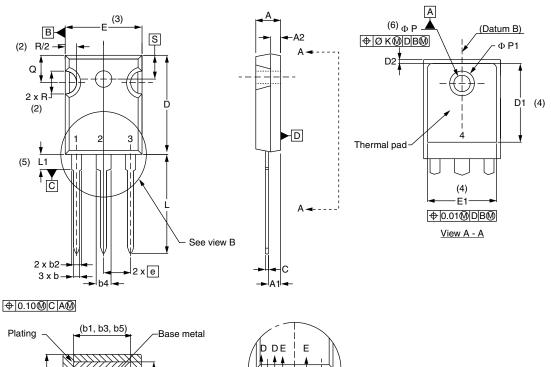
M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-30TPS12LHM3	25	500	Antistatic plastic tubes			

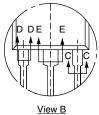
LINKS TO RELATED DOCUMENTS					
Dimensions TO-247AD 3L <u>www.vishay.com/doc?95626</u>					
Part marking information TO-247AD 3L <u>www.vishay.com/doc?95007</u>					

TO-247AD 3L

DIMENSIONS in millimeters and inches



Plating _	(b1, b3, b5)	-Base meta
(c)		c1
	(b, b2, b4) — (4)	
9	Section C - C, D - D	<u>, E - E</u>



SYMBOL	MILLIN	IETERS	INCHES		NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	IVIILLIIV	IEIENO	INCHES		NOTES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	2.54		0.0)10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	' BSC	

INCHES

MILLIMETERS

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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